



## RLT808-100G

- Infrared Laser Diode
- 808 nm, 100 mW
- Single Mode
- 9 mm TO-Can, Flat Window



### Description

**RLT808-100G** is an IR laser diode, typically emitting at 808 nm. It features a 3 x 1  $\mu\text{m}$  emitter with **single transverse mode** emission and wide operating temperature range.

**RLT808-100G** comes in 9 mm TO-Can package with **integrated PD**.

**Additional options** like closer peak wavelength selection are available on request.

### Maximum Rating ( $T_{\text{CASE}} = 25^{\circ}\text{C}$ )

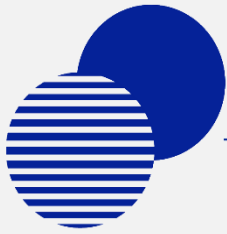
Parameter	Symbol	Values		Unit
		Min.	Max.	
Reverse Voltage	$V_R$		2.0	V
PD Reverse Voltage	$V_{PDR}$		30	V
Operating Temperature	$T_{\text{OPR}}$	- 10	+ 50	$^{\circ}\text{C}$
Storage Temperature	$T_{\text{STG}}$	- 40	+ 80	$^{\circ}\text{C}$
Soldering Temperature (max. 3s)	$T_{\text{SOL}}$		+ 260	$^{\circ}\text{C}$

### Electro-Optical Characteristics ( $T_{\text{CASE}} = 25^{\circ}\text{C}$ )

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Peak Wavelength *	$\lambda_P$	798	808	818	nm
Spectral Width (FWHM)	$\Delta\lambda$		2		nm
Output Power	$P_O$		100		mW
Emitter Size	$A$		3 x 1		$\mu\text{m}$
Threshold Current	$I_{\text{th}}$		35	60	mA
Operating Current	$I_F$		140	160	mA
Operating Voltage	$V_F$		2.3	2.8	V
PD Current	$I_{\text{PD}}$		0.1		mA
Slope Efficiency	$\eta$		1.0		mW/mA
Beam Divergence (FWHM)	parallel		$\theta_{\perp}$	28	deg
	perpendicular		$\theta_{\parallel}$	10	deg

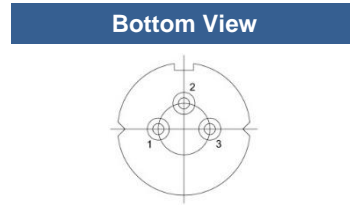
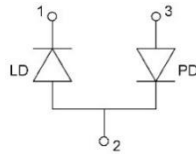


\* optional: down to  $\pm 5$  nm



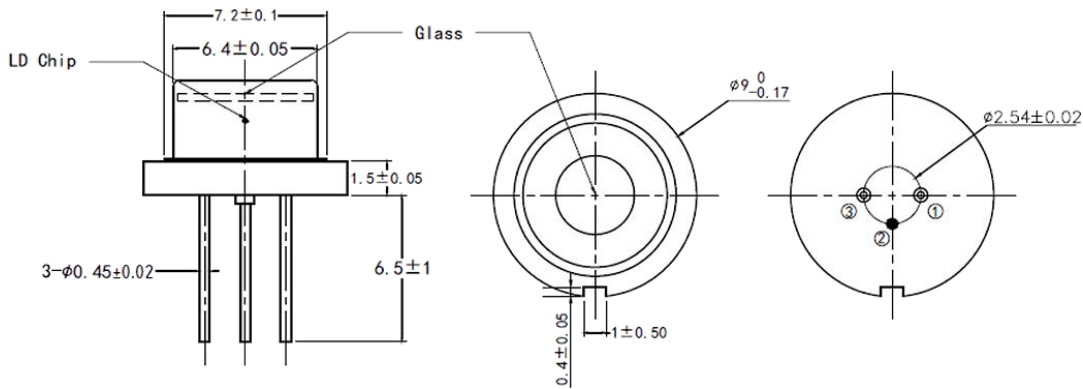
## Electrical Connection

Pin Configuration*	
PIN #	Function
1	LD Cathode
2	LD Anode, PD Cathode, Case
3	PD Anode



\* subject to change

## Outline Dimension



All dimensions in mm



## Precautions

### Safety

**Caution:** Laser light emitted from any laser diode may be harmful to the human eye. Avoid looking directly into the laser diode's aperture when the diode is in operation.

**Note:** The use of optical lenses with this laser diode will increase eye hazard



### ESD Caution

Always do handle laser diodes with extreme care to **prevent electrostatic discharge**, the primary cause of unexpected diode failure. To prevent ESD related failures we strongly advise to always **wearing wrist straps**, and **grounding all applicable work surfaces**, when handling laser diodes



### Operating Considerations

We strongly advise to only operate this laser diode with a current source. The current of a laser diode is an exponential function of the voltage across it. **Usage of current regulated drive circuits is mandatory.**

Laser diodes may be damaged by excessive drive currents or switching transients

It is advised, to operate the laser diode at the lowest temperature possible, and to never exceed maximum specifications as outlined in the datasheet. Device degradation will accelerate with increased temperature. **Proper heat sinking will greatly enhance stability and life-time of the laser diode.**

© All Rights Reserved

The above specifications are for reference purpose only and subjected to change without prior notice